# 2N6383 2N6384 2N6385



### **NPN Silicon Power Darlington Transistors**

Rev. V3

#### **Features**

- Available in JAN, JANTX, JANTXV per MIL-PRF-19500/523
- TO-3 (TO-204AA) Package
- Designed for Power Amplifier and Shunt and Series Regulator Applications



## Electrical Characteristics (T<sub>A</sub> = +25°C unless otherwise noted)

Parameter	Test Conditions	Symbol	Units	Min.	Max.
Collector - Emitter Breakdown Voltage	I <sub>C</sub> = 200 mA dc 2N6383 2N6384 2N6385	V <sub>(BR)CEO</sub>	V dc	40 60 80	_
Collector - Emitter Breakdown Voltage	$I_{C}$ = 200 mA dc, $R_{BB}$ = 100 $\Omega$ 2N6383 2N6384 2N6385	V <sub>(BR)CER</sub>	V dc	40 60 80	_
Collector - Base Cutoff Current	V <sub>CE</sub> = 40 V dc, 2N6383 V <sub>CE</sub> = 60 V dc, 2N6384 V <sub>CE</sub> = 80 V dc, 2N6385	I <sub>CBO1</sub>	mA dc	_	1.0
Emitter - Base Cutoff Current	V <sub>EB</sub> = 5 V dc	I <sub>EBO</sub>	mA dc	_	5.0
Collector - Emitter Cutoff Current	V <sub>CE</sub> = 40 V dc, 2N6383 V <sub>CE</sub> = 60 V dc, 2N6384 V <sub>CE</sub> = 80 V dc, 2N6385	I <sub>CEO</sub>	mA dc	_	1.0
Collector - Emitter Cutoff Current	$V_{CE}$ = 40 V dc, $V_{BE}$ = -1.5 Vdc, 2N6383 $V_{CE}$ = 60 V dc, $V_{BE}$ = -1.5 Vdc, 2N6384 $V_{CE}$ = 80 V dc, $V_{BE}$ = -1.5 Vdc, 2N6385	I <sub>CEX1</sub>	μA dc	_	100
	V = 2 V do L = 5 0 A do			1 000	20,000
Forward Current Transfer Ratio	$V_{CE} = 3 \text{ V dc}, I_C = 5.0 \text{ A dc}$ $V_{CE} = 3 \text{ V dc}, I_C = 10 \text{ A dc}$	h <sub>FE1</sub>	-	1,000 100	20,000
Saturation Voltage and Resistance	$I_C = 5.0 \text{ A dc}, I_B = 10 \text{ mA dc}$ $I_C = 10 \text{ A dc}, I_B = 0.1 \text{ A dc}$	V <sub>CE(SAT)1</sub> V <sub>CE(SAT)2</sub>	V dc	_	2.0 3.0
Base - Emitter Voltage (Unsaturated)	$V_{CE}$ = 3.0 V dc, $I_{C}$ = 5.0 A dc $V_{CE}$ = 3.0 V dc, $I_{C}$ = 10 A dc	$V_{\text{BE(on)1}}$ $V_{\text{BE(on)2}}$	V dc	_	2.8 4.5
Collector-Emitter Cutoff Current	$T_{A} = +150^{\circ}\text{C}$ $V_{CE} = 40 \text{ V dc}, V_{BE} = -1.5 \text{ Vdc}, 2\text{N}6383$ $V_{CE} = 60 \text{ V dc}, V_{BE} = -1.5 \text{ Vdc}, 2\text{N}6384$ $V_{CE} = 80 \text{ V dc}, V_{BE} = -1.5 \text{ Vdc}, 2\text{N}6385$		mA dc	_	3.0
Forward - Current Transfer Ratio	$T_A = -55^{\circ}C$ $V_{CE} = 3.0 \text{ V dc}, I_C = 5.0 \text{ A dc}$	h <sub>FE3</sub>		200	

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## Electrical Characteristics (T<sub>A</sub> = +25°C unless otherwise noted)

Parameter	Test Conditions	Symbol	Units	Min.	Max.
Magnitude of Small-Signal Short-Circuit Forward-Current Transfer Ratio	I <sub>C</sub> = 1 A dc, V <sub>CE</sub> = 5 V dc, f = 1 MHz	h <sub>fe</sub>	-	20	300
Open-Circuit Output Capacitance	$V_{CB} = 10 \text{ V dc}, I_E = 0, 100 \text{ kHz} \le f \le 1 \text{ MHz}$	C <sub>obo</sub>	pF	_	200
Turn-On Time	$V_{CC}$ = 30 V dc; $I_{C}$ = 5 A dc, $I_{B1}$ = 20 mA dc	t <sub>on</sub>	μs	_	2.5
Turn-Off Time	$V_{CC} = 30 \text{ V dc}$ ; $I_C = 5 \text{ A dc}$ , $I_{B1} = -I_{B2} = 20 \text{ mA dc}$	t <sub>off</sub>	μs	_	10

## Absolute Maximum Ratings (T<sub>A</sub> = +25°C unless otherwise noted)

Ratings	Symbol	2N6383	2N6384	2N6385	Units
Collector - Emitter Voltage	V <sub>CEO</sub>	40	60	80	V dc
Collector - Base Voltage	V <sub>CBO</sub>	40	60	80	V dc
Emitter - Base Voltage	V <sub>EBO</sub>	5			V dc
Collector Current	I <sub>C</sub>	10			A dc
Base Current	I <sub>B</sub>	0.25			A dc
Total Power Dissipation  @ $T_A = +25^{\circ}C^{(1)}$ @ $T_C = +25^{\circ}C^{(2)}$	P <sub>T</sub>	6 100			W
Operating & Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175			°C

<sup>(1)</sup> Derate linearly @ 34.2 mW /  $^{\circ}$ C above  $T_{A} > 25 ^{\circ}$ C.

#### **Thermal Characteristics**

Characteristics	Symbol	Max. Value
Thermal Resistance, Junction to Case	$R_{ heta JC}$	1.75°C/W

Safe Operating A	ea
DC Tests:	$T_C$ = +25 °C, I Cycle, t = 1.0 s
Test 1: Test 2: Test 3:	$V_{CE}$ = 10 Vdc, $I_{C}$ = 10 A dc, All Types $V_{CE}$ = 30 Vdc, $I_{C}$ = 3.33 A dc, All Types $V_{CE}$ = 40 Vdc, $I_{C}$ = 1.5 A dc, 2N6383 $V_{CE}$ = 60 Vdc, $I_{C}$ = 0.4 A dc, 2N6384 $V_{CE}$ = 80 Vdc, $I_{C}$ = 0.16 A dc, 2N6385

<sup>(2)</sup> Derate linearly @ 571 mW / °C above T<sub>C</sub> > 25°C.



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#### **Outline Drawing (TO-3)**

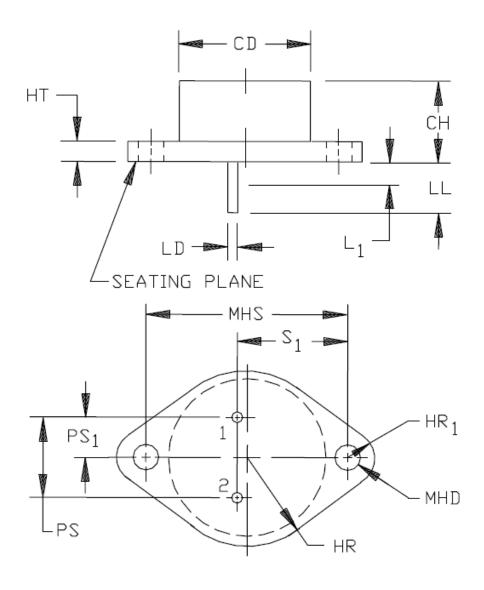


FIGURE 1. Physical dimensions (TO-204AA, formerly TO-3)



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#### **Outline Drawing (TO-3)**

Symbol	Dimensions				Notes
	Inc	Inches Millim		neters	
	Min	Max	Min	Max	
CD		.875		22.23	5
CH	.250	.450	6.35	11.43	
HR	.495	.525	12.57	13.34	6
HR <sub>1</sub>	.131	.188	3.33	4.78	6
HT	.050	.135	1.27	3.43	
LD	.038	.043	0.97	1.09	7, 8, 9
LL	.312	.500	7.92	12.7	
L <sub>1</sub>		.050		1.27	
MHD	.151	.161	3.84	4.09	10
MHS	1.177	1.197	29.90	30.40	
PS	.420	.440	10.67	11.18	8
PS <sub>1</sub>	.205	.225	5.21	5.72	7, 8
S <sub>1</sub>	.655	.675	16.64	17.15	7, 8

#### NOTES:

- 1. Dimensions are in inches. Millimeters are given for general information only.
- Terminal 1 is the emitter and terminal 2 is the base. The collector shall be electrically connected to the case.
- The seating plane of the header shall be flat within .001 inch (0.03 mm) concave to .004 inch (0.10 mm) convex inside a .930 inch (23.62 mm) diameter circle on the center of the header and flat within .001 inch (0.03 mm) concave to .006 inch (0.15 mm) convex overall.
- Mounting holes (MHD) shall be deburred on the seating plane side.
- 5. Body contour is optional within zone defined by dimension CD.
- 6. Applies to all sides (HR) or both ends (HR<sub>1</sub>).
- Applies to both terminals.
- Measurement for this dimension shall be taken at points .050 inch (1.27 mm) to .055 inch (1.40 mm) below the seating plane. When gauge is not used, measurement shall be made at seating plane.
- 9. Lead diameter shall not exceed twice dimension LD within dimension L1.
- Applies to both holes.
- In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.

FIGURE 1. Physical dimensions (TO-204AA, formerly TO-3) - Continued.



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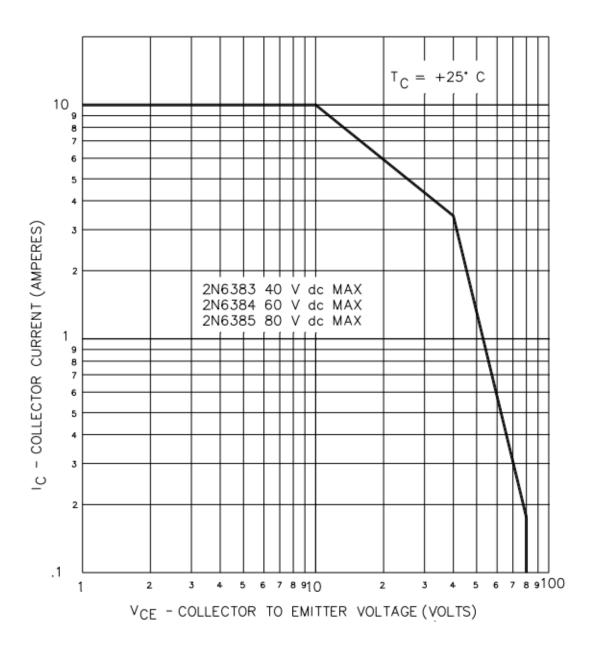
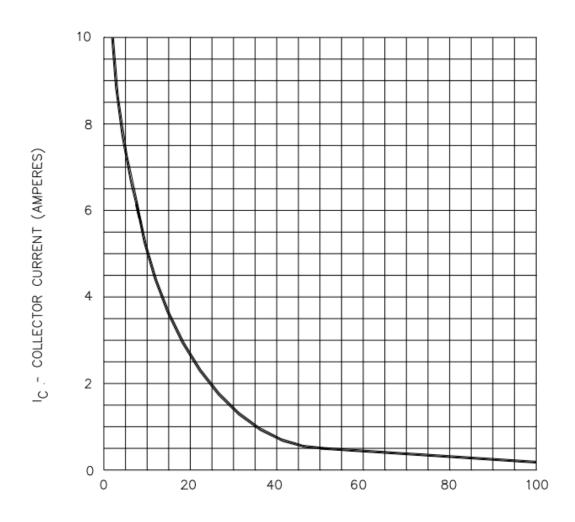


FIGURE 3. Maximum safe operating graph (continuous dc).



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L - INDUCTANCE (MILLIHENRIES)

FIGURE 4. Safe operating area for switching between saturation and cutoff (unclamped inductive load).

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